

## Nanomechanical properties of silicon surfaces nanostructured by excimer laser

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**Journal** [Science and Technology of Advanced Materials](#) [Create an alert](#) [RSS this journal](#)

**Issue** [Volume 11, Number 2](#)

**Citation** Prashant Kumar and M S R N Kiran 2010 *Sci. Technol. Adv. Mater.* **11** 025003  
doi: [10.1088/1468-6996/11/2/025003](https://doi.org/10.1088/1468-6996/11/2/025003)

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**Abstract** Excimer laser irradiation at ambient temperature has been employed to produce nanostructured silicon surfaces. Nanoindentation was used to investigate the nanomechanical properties of the deformed surfaces as a function of laser parameters, such as the angle of incidence and number of laser pulses at a fixed laser fluence of 5 J cm<sup>-2</sup>. A single-crystal silicon [311] surface was severely damaged by laser irradiation and became nanocrystalline with an enhanced porosity. The resulting laser-treated surface consisted of nanometer-sized particles. The pore size was controlled by adjusting the angle of incidence and the number of laser pulses, and varied from nanometers to microns. The extent of nanocrystallinity was large for the surfaces irradiated at a small angle of incidence and by a high number of pulses, as confirmed by x-ray diffraction and Raman spectroscopy. The angle of incidence had a stronger effect on the structure and nanomechanical properties than the number of laser pulses.

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[61.82.Rx Nanocrystalline materials](#)  
[61.80.Ba Ultraviolet, visible, and infrared radiation effects \(including laser radiation\)](#)  
[68.35.Gy Mechanical properties; surface strains](#)  
[78.30.Am Elemental semiconductors and insulators](#)  
[78.67.Bf Nanocrystals and nanoparticles](#)

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**Dates** Issue 2 (April 2010)  
Received 18 十二月 2009 , accepted for publication 17 三月 2010  
Published 13 五月 2010

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